# NSN 5961-01-564-4533

Unitized Semiconductor Devices - Page 1 of 1



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1 semiconductor device diode

**Mounting Method:** 

Terminal

### Voltage Rating In Volts Per Characteristic:

100.0 repetitive peak reverse voltage single semiconductor and 1.0 forward voltage, dc single semiconductor

## **Current Rating Per Characteristic:**

200.00 milliamperes collector current, dc single semiconductor

### **Power Rating Per Characteristic:**

350.0 milliwatts collector power dissipation peak single semiconductor

### **Maximum Operating Tempurature Per Measurement Point:**

150.0 degrees celsius junction

**Special Features:** 

Small signal diodes

### **Terminal Type And Quantity:**

3 tab, solder lug

Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

No

Fiig:

A110a0